

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	11	(IC or semiconductor or (integrated adj circuit)) with encrypt\$ with engine and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/18 16:04
S2	2	"6591365".pn. and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/18 16:05
S3	1	(US-5563950-\$).did.	USPAT	OR	ON	2005/05/23 10:54
S4	1	S3 and register	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:06
S5	11771	lithograph\$ with semiconductor and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:06
S6	0	lithograph\$ with semiconductor with encrypt\$ with key and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:06
S7	54	lithograph\$ with semiconductor with key and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:07
S8	34	lithograph\$ and "713".clas. and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:30
S9	9	lithograph\$ with IC with key and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:12
S10	0	lithograph\$ with encrypt\$ with key and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:12
S11	1588	lithograph\$ with IC and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:12
S12	0	lithograph\$ with IC and ("713". clas. or "380".clas.)and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:12

S13	0	lithograph\$ with IC and ("713". clas. or "380".clas.) and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:12
S14	0	lithograph\$ with IC and "713". clas. and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:12
S15	1588	lithograph\$ with IC and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:13
S16	0	lithograph\$ with IC AND "380". CLAS. and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:13
S17	0	lithograph\$ with IC with encrypt\$ and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:13
S18	9	lithograph\$ with IC with key and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:13
S19	4127	laser with etch\$ with (ic or semiconductor) and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:31
S20	1	laser with etch\$ with (ic or semiconductor) and "713".clas. and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:31
S21	1	laser with etch\$ with (ic or semiconductor) with key and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 14:31
S22	2	(US-20030093661-\$).did. or (US-5563950-\$).did.	US-PGPUB; USPAT	OR	ON	2005/05/23 14:32
S23	1	S22 and laser	US-PGPUB; USPAT	OR	ON	2005/05/23 15:36
S24	2	key with stor\$3 with fuse with (semiconductor or IC) and @aD<="20011127"	US-PGPUB; USPAT	OR	ON	2005/05/23 15:40
S25	8	protect\$ with data with fuse with (semiconductor or IC) and @aD<="20011127"	US-PGPUB; USPAT	OR	ON	2005/05/23 15:40
S26	3	(US-20030093661-\$ or US-20020145931-\$).did. or (US-5563950-\$).did.	US-PGPUB; USPAT	OR	ON	2005/05/23 16:23

S27	0	S26 and silicon	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 16:24
S28	272	semiconductor with silicon adj die and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 16:24
S29	0	semiconductor with silicon adj die with protect\$ with data and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 16:24
S30	5	semiconductor with silicon adj die with protect\$ and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 17:52
S31	0	symetric\$ with asymetric\$ with (IC or semiconductor) and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 17:52
S32	52	symetric\$ with asymetric\$ and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 17:52
S33	16970	symmetric\$ with asymmetric\$ and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 17:52
S34	144	symmetric\$ with asymmetric\$ with (IC or semiconductor) and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 17:53
S35	1	symmetric\$ with asymmetric\$ with (IC or semiconductor) with encrypt\$ and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 17:53
S36	1	symmetric\$ with asymmetric\$ with (IC or semiconductor) with \$crypt\$ and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 17:53
S37	762	symmetric\$ with asymmetric\$ with \$crypt\$ and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 17:54
S38	570	symmetric\$ with asymmetric\$ with encrypt\$ and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 17:54

S39	456	symmetric\$ with asymmetric\$ with encrypt\$ with key and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 17:54
S40	1	symmetric\$ with asymmetric\$ with encrypt\$ with key with decrypt\$ with together and @aD<="20011127"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/05/23 17:54